

FEATURES

- Wide current range
- High voltage ratings up to 4000 V
- High surge current capabilities
- Diffused junction

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

TECHNICAL DATA

DEVICE TYPE	V _{RRM} (V)	V _{RSM} (V)
DS2007SD36	3600	3700
DS2007SD38	3800	3900
DS2007SD40	4000	4100



CURRENT RATINGS

T_{case} = 75°C unless otherwise stated

Symbol	Parameter	Conditions	Max.	Units
Double Side Cooled				
I _{F(AV)}	Mean forward current	Half wave resistive load	1594	A
I _{F(RMS)}	RMS value	-	2504	A
I _F	Continuous (direct) forward current	-	2295	A
Single Side Cooled (Anode side)				
I _{F(AV)}	Mean forward current	Half wave resistive load	1144	A
I _{F(RMS)}	RMS value	-	1797	A
I _F	Continuous (direct) forward current	-	1553	A

$T_{case} = 100^\circ\text{C}$ unless otherwise stated

Symbol	Parameter	Conditions	Max.	Units
Double Side Cooled				
$I_{F(AV)}$	Mean forward current	Half wave resistive load	1225	A
$I_{F(RMS)}$	RMS value	-	1923	A
I_F	Continuous (direct) forward current	-	1720	A
Single Side Cooled (Anode side)				
$I_{F(AV)}$	Mean forward current	Half wave resistive load	820	A
$I_{F(RMS)}$	RMS value	-	1287	A
I_F	Continuous (direct) forward current	-	1050	A

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I_{FSM}	Surge (non-repetitive) forward current	10ms half sine; $T_{case} = 150^\circ\text{C}$ $V_R = 50\% V_{RRM} - 1/4 \sin$	20.0	kA
I^2t	I^2t for fusing		2.0×10^6	A^2s
I_{FSM}	Surge (non-repetitive) forward current	10ms half sine; $T_{case} = 150^\circ\text{C}$ $V_R = 0$	25.0	kA
I^2t	I^2t for fusing		3.125×10^6	A^2s

THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions	Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	-	0.022	$^\circ\text{C}/\text{W}$
		Single side cooled	Anode dc	-	$^\circ\text{C}/\text{W}$
			Cathode dc	-	$^\circ\text{C}/\text{W}$
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 19.5kN with mounting compound	Double side	-	$^\circ\text{C}/\text{W}$
			Single side	-	$^\circ\text{C}/\text{W}$
T_{vj}	Virtual junction temperature	Forward (conducting)	-	160	$^\circ\text{C}$
		Reverse (blocking)	-	150	$^\circ\text{C}$
T_{stg}	Storage temperature range		-55	175	$^\circ\text{C}$
-	Clamping force		18.0	22.0	kN

CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Max.	Units
V_{FM}	Forward voltage	At 3400A peak, $T_{case} = 25^\circ C$	-	1.6	V
I_{RRM}	Peak reverse current	At V_{RRM} , $T_{case} = 150^\circ C$	-	75	mA
Q_s	Total stored charge	$I_F = 2000A$, $dI_{RR}/dt = 3A/\mu s$, $T_{case} = 150^\circ C$, $V_R = 100V$	-	3500	μC
I_{RR}	Peak recovery current		-	110	A
V_{TO}	Threshold voltage	At $T_{vj} = 150^\circ C$	-	0.82	V
r_T	Slope resistance	At $T_{vj} = 150^\circ C$	-	0.29	$m\Omega$

CURVES

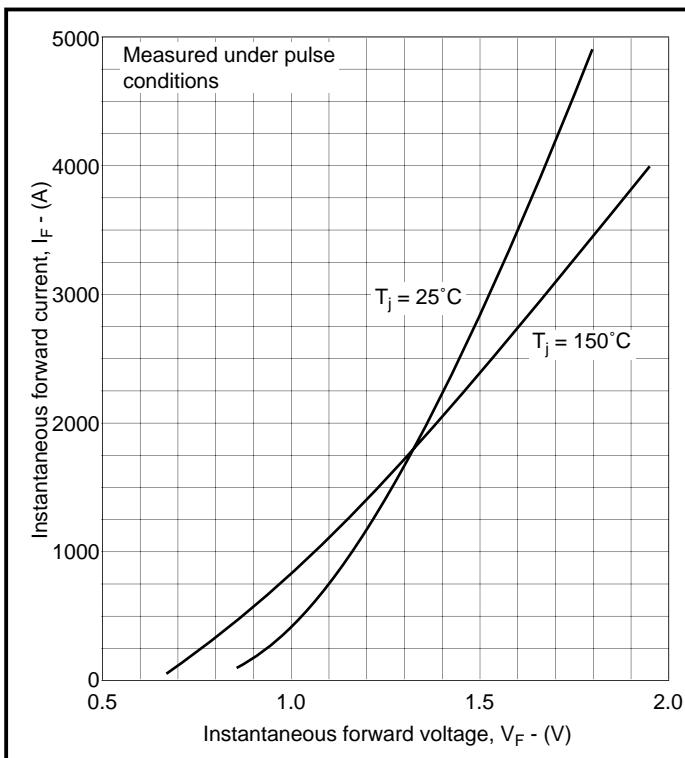


Fig.2 Maximum (limit) forward characteristics

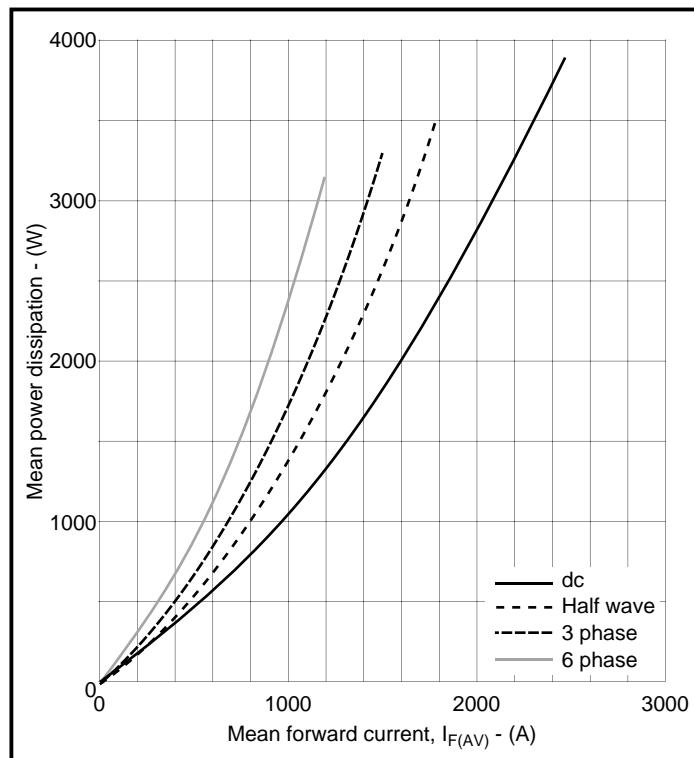


Fig.3 Dissipation curves

V_{FM} Equation:-

$$V_{FM} = A + B \ln(I_F) + C.I_F + D.\sqrt{I_F}$$

Where

$$A = 0.658789$$

$$B = -0.01706$$

$$C = 0.000194$$

$$D = 0.010358$$

these values are valid for $T_j = 125^\circ C$ for I_F 500A to 5000A

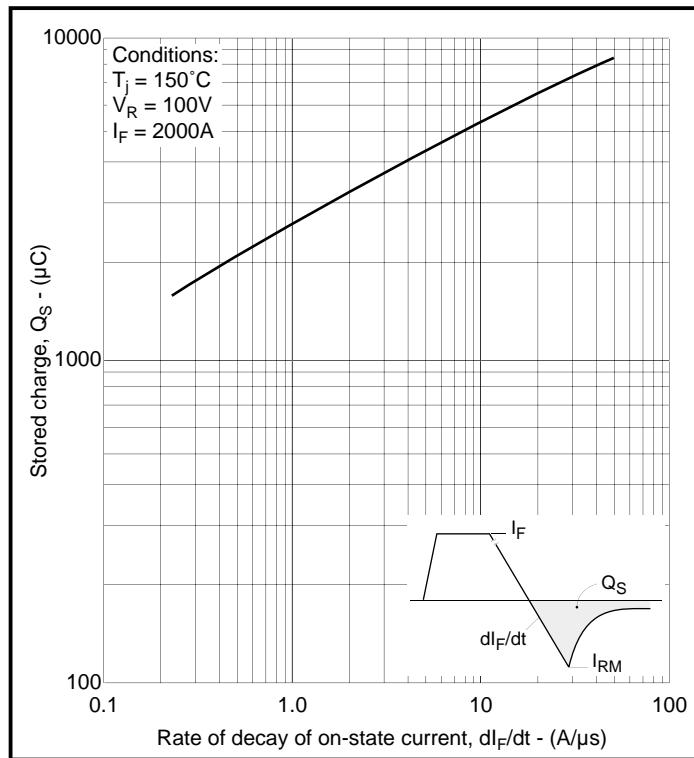


Fig.4 Total stored charge

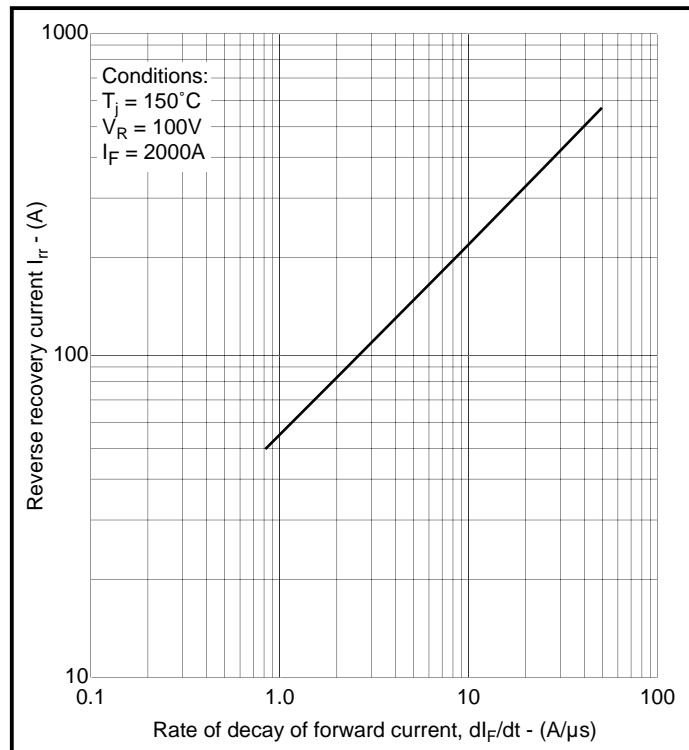
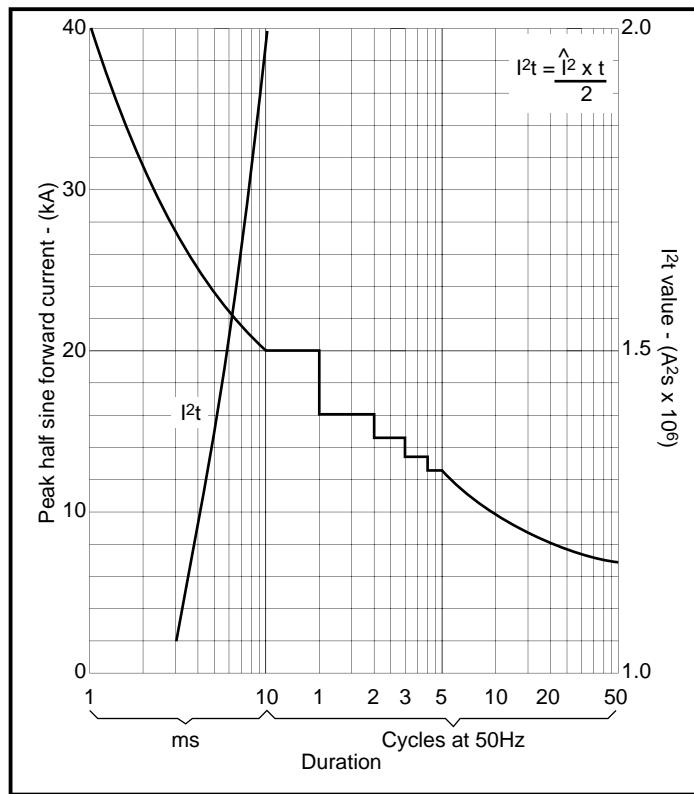


Fig.5 Maximum reverse recovery current



**Fig.6 Surge (non-repetitive) forward current vs time
(with 50% V_{RRM} at $T_{case} 150^\circ\text{C}$)**

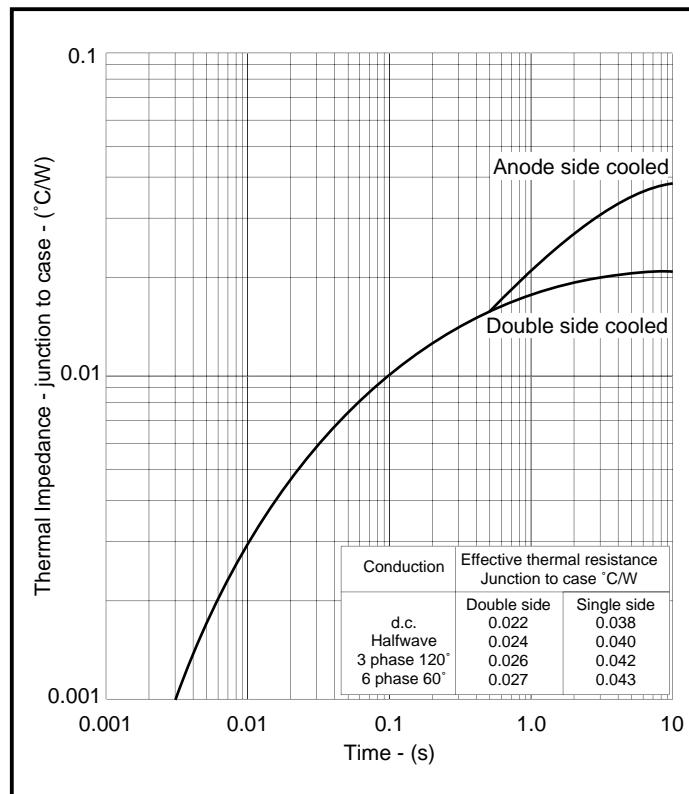
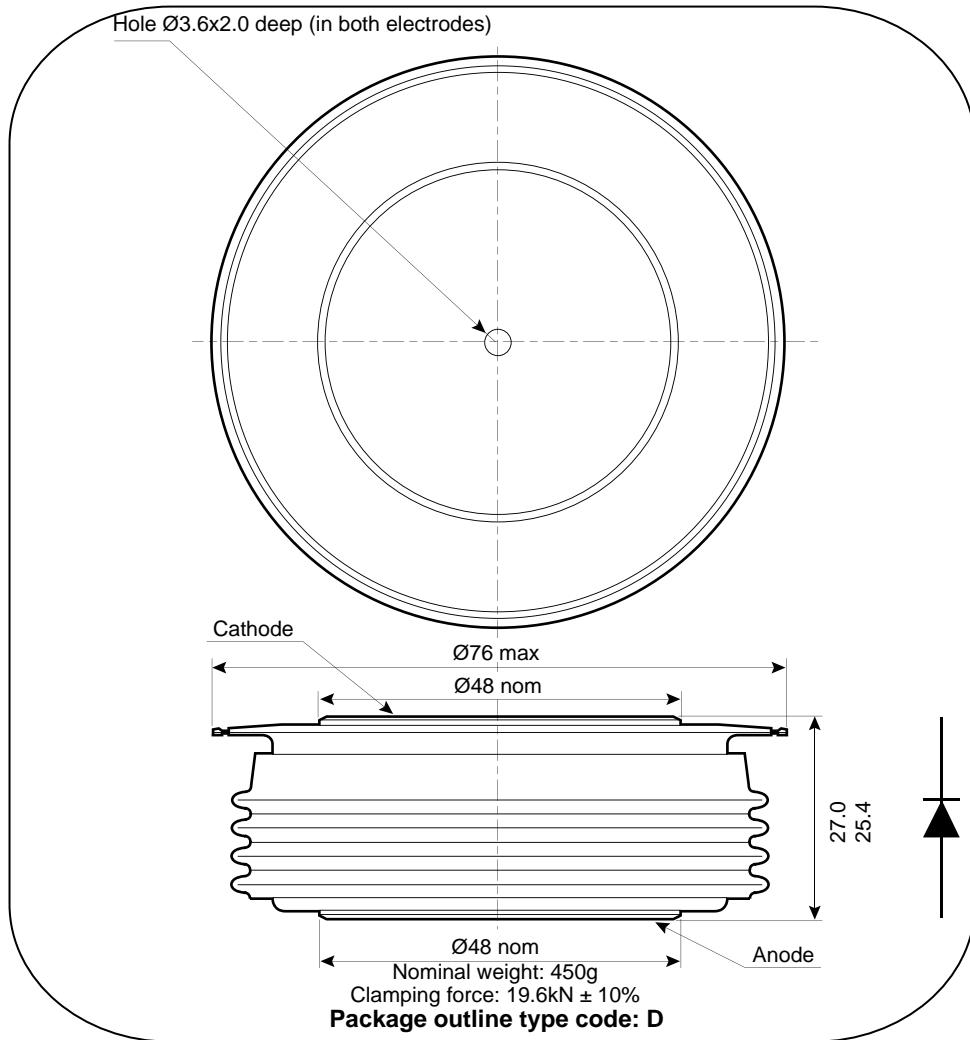


Fig.7 Maximum (limit) transient thermal impedance - junction to case

PACKAGE OUTLINE



All dimensions are in mm.

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